



### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Features**

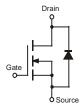
- Low Gate Charge
- Low  $R_{DS(ON)}$ :
  - $30 \text{ m}\Omega @V_{GS} = 10V$
  - $40 \text{ m}\Omega$  @V<sub>GS</sub> = 4.5V
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 3)
- · Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 4)

## **Mechanical Data**

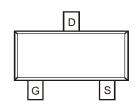
- Case: SC-59
- Case Material Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
   Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)







**Equivalent Circuit** 



Pin Configuration

## Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		$V_{DSS}$	30	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Drain Current (Note 1) Continuous	T <sub>A</sub> = 25°C T <sub>A</sub> = 70°C	I <sub>D</sub>	6 5	А
Pulsed Drain Current (Note 2)		I <sub>DM</sub>	24	Α
Body-Diode Continuous Current (Note 1)		I <sub>S</sub>	2.25	Α

## Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	$P_{D}$	1.4	W
Thermal Resistance, Junction to Ambient (Note 1) t ≤10s	$R_{ hetaJA}$	90	°C /W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 1. Device mounted on 1"x1", FR-4 PC board with 2 oz. Copper and test pulse width t ≤10s.
- 2. Repetitive Rating, pulse width limited by junction temperature.
- 3. No purposefully added lead.
- 4. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

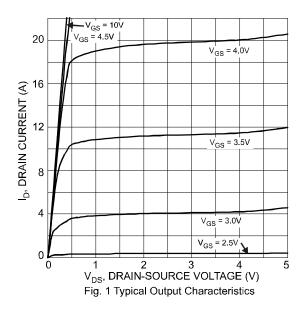


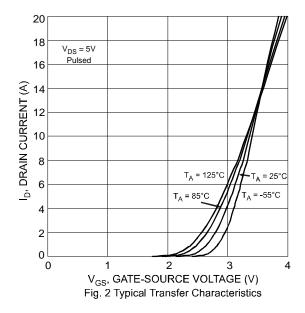
## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

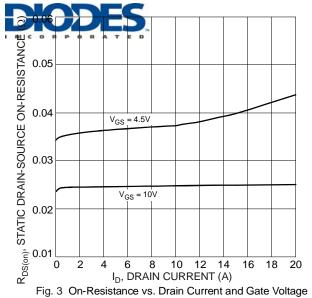
Characteristic			Min	Тур	Max	Unit	Test Condition
STATIC PARAMETERS							
Drain-Source Breakdown Voltage			30			V	$I_D = 250 \mu A, V_{GS} = 0 V$
Zero Gate Voltage Drain Current	$T_J = 25$ °C $T_J = 55$ °C	I <sub>DSS</sub>			1 5	μΑ	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V
Gate-Body Leakage Current		I <sub>GSS</sub>			±100	nA	$V_{DS} = 0V, V_{GS} = \pm 20V$
Gate Threshold Voltage		V <sub>GS(th)</sub>	1.0		2.1	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance (Note 5)		R <sub>DS (ON)</sub>		25 36	30 40	$m\Omega$	$V_{GS} = 10V, I_D = 6A$ $V_{GS} = 4.5V, I_D = 5A$
Forward Transconductance (Note 5)		<b>g</b> FS		5		S	$V_{DS} = 10V, I_D = 8A$
Diode Forward Voltage (Note 5)				0.7	1.1	V	$I_S = 2.25A$ , $V_{GS} = 0V$
DYNAMIC PARAMETERS (Note 6)							
Total Gate Charge		$Q_g$	_	10.5		nC	$V_{GS} = 5V$ , $V_{DS} = 15V$ , $I_{D} = 6A$
Gate-Source Charge		$Q_{gs}$		3.8		nC	$V_{GS} = 10V, V_{DS} = 15V, I_D = 6A$
Gate-Drain Charge		$Q_{gd}$		2.9		nC	$V_{GS} = 10V, V_{DS} = 15V, I_D = 6A$
Turn-On Delay Time		t <sub>D(on)</sub>		11		ns	
Turn-On Rise Time		t <sub>r</sub>		7		ns	$V_{DD} = 15V, V_{GS} = 10V,$
Turn-Off Delay Time		t <sub>D(off)</sub>		63		ns	$R_D = 1.8\Omega$ , $R_G = 6\Omega$
Turn-Off Fall Time		t <sub>f</sub>	_	30		ns	
Input Capacitance		Ciss		755		pF	V 40V V 0V
Output Capacitance		Coss		136		рF	$V_{DS} = 10V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance		C <sub>rss</sub>	_	108		рF	1 - 1.0IVII IZ

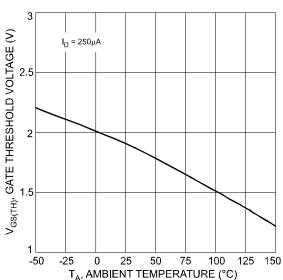
Notes:

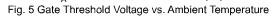
- 5. Test pulse width t = 300ms.
- 6. Guaranteed by design. Not subject to production testing.

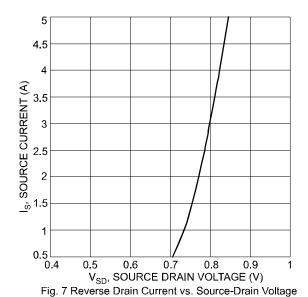


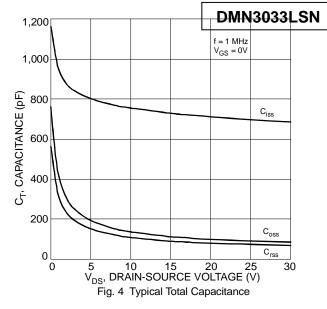












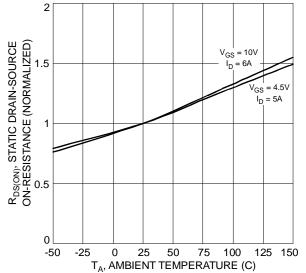


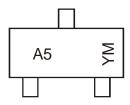
Fig. 6 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature



Part Number	Case	Packaging
DMN3033LSN-7	SC-59	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**

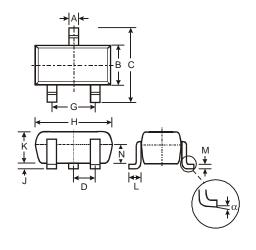


A5 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: U = 2007) M = Month (ex: 9 = September)

Date Code Key

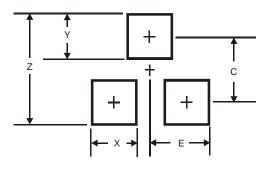
Year	2007	200	8	2009	2010	20	11	2012	2013	20	14	2015
Code	U	V		W	Х	`	Y	Z	Α	E	3	С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

## **Package Outline Dimensions**

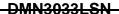


SC-59						
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
C	2.70	3.00	2.80			
D	-	-	0.95			
G	-	-	1.90			
Н	2.90	3.10	3.00			
7	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
M	0.10	0.20	0.15			
N	0.70	0.80	0.75			
α	0°	8°	-			
All Dimensions in mm						

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	3.4
Х	0.8
Υ	1.0
С	2.4
E	1.35





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